

# **HD74HC680**

## 12-bit Address Comparator

REJ03D0641-0200 (Previous ADE-205-527) Rev.2.00 Mar 30, 2006

#### **Description**

The HD74HC680 address comparator simplifies addressing of memory boards and/or other peripheral devices. The four P inputs are normally hard wired with a preprogrammed address. An internal decoder determines what input information applied to the 12 A inputs must be low or high to cause a low state at the output (Y). For example, a positive-logic bit combination of 0111 (decimal 7) at the P input determines that inputs  $A_1$  through  $A_7$  must be low and that inputs  $A_8$  through  $A_{12}$  must be high to cause the output to go low. Equality of the address applied at the A inputs to the preprogrammed address is indicated by the output being low.

The HD74HC680 features a transparent latch and a latch enable input (C). When C is high, the device is in the transparent mode. When C is low, the previous logical state of Y is latched.

#### **Features**

• High Speed Operation

• High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage:  $V_{CC} = 2 \text{ to } 6 \text{ V}$ 

• Low Input Current: 1 μA max

• Low Quiescent Supply Current:  $I_{CC}$  (static) = 4  $\mu$ A max (Ta = 25°C)

• Ordering Information

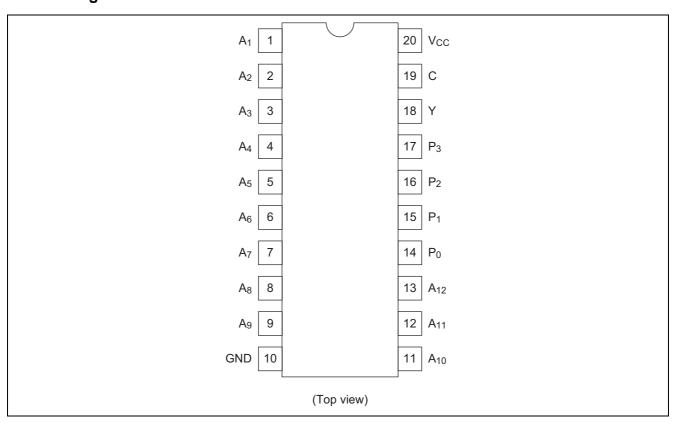
Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC680RPEL	SOP-20 pin (JEDEC)	PRSP0020DC-A (FP-20DBV)	RP	EL (1,000 pcs/reel)

## **Function Table**

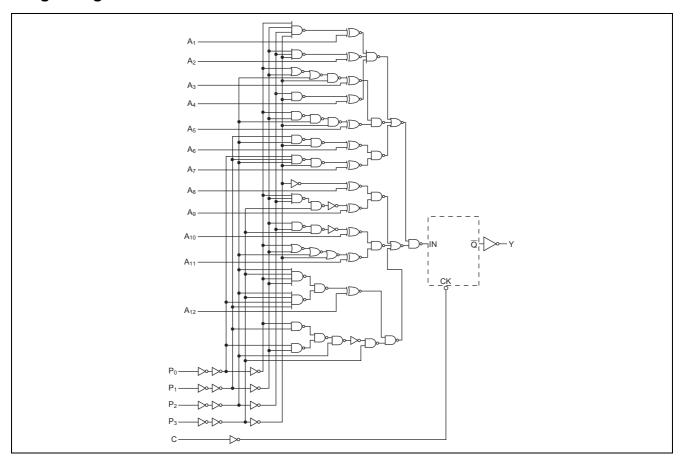
	Inputs																
С	P <sub>3</sub>	P <sub>2</sub>	P <sub>1</sub>	P <sub>0</sub>	<b>A</b> <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	<b>A</b> <sub>4</sub>	<b>A</b> <sub>5</sub>	A <sub>6</sub>	<b>A</b> <sub>7</sub>	A <sub>8</sub>	A <sub>9</sub>	A <sub>10</sub>	A <sub>11</sub>	A <sub>12</sub>	Output Y
Н	L	L	L	L	Ι	Ι	Н	Ι	Ι	Ι	Ι	Н	Н	Н	Н	Н	L
Н	L	L	L	Ι	L	Ι	Н	Ι	Ι	Ι	Ι	Н	Н	Н	Н	Н	L
Н	L	L	Н	L	L	L	Н	Ι	Ι	Ι	Ι	Н	Н	Н	Н	Н	L
Н	L	L	Н	Н	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	L
Н	L	Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	L
Н	L	Н	L	Н	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	L
Н	L	Н	Н	L	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	L
Н	L	Н	Н	Н	L	L	L	L	L	L	L	Н	Н	Н	Н	Н	L
Н	Н	L	L	L	L	L	L	L	L	L	L	L	Н	Н	Н	Н	L
Н	Н	L	L	Н	L	L	L	L	L	L	L	L	L	Н	Н	Н	L
Н	Н	L	Н	L	L	L	L	L	L	L	L	L	L	L	Н	Н	L
Н	Н	L	Н	Н	L	L	L	L	L	L	L	L	L	L	L	Н	L
Н	Н	Н	L	L	L	L	L	L	L	L	L	L	L	L	L	L	L
Н	Н	Н	L	Н	Χ	Х	Х	Χ	Χ	Χ	Χ	Х	Х	Х	Х	Х	Н
Н	Н	Н	Н	L	Χ	Χ	Х	Х	Χ	Χ	Χ	Х	Х	Х	Х	Х	Н
Н	Н	Н	Н	Н	L	L	L	L	L	L	L	L	L	L	L	L	L
Н	H All other combinations								Н								
L	Any combination								Latched								

H: high levelL: low levelX: irrelevant

## **Pin Arrangement**



#### **Logic Diagram**



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
Input / Output voltage	V <sub>IN</sub> , V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> +0.5	V
Input / Output diode current	I <sub>IK</sub> , I <sub>OK</sub>	±20	mA
Output current	I <sub>OUT</sub>	±25	mA
V <sub>CC</sub> , GND current	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA
Power dissipation	P <sub>T</sub>	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

### **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V <sub>CC</sub>	2 to 6	V	
Input / Output voltage	V <sub>IN</sub> , V <sub>OUT</sub>	0 to V <sub>CC</sub>	V	
Operating temperature	Та	-40 to 85	°C	
		0 to 1000		V <sub>CC</sub> = 2.0 V
Input rise / fall time*1	$t_r$ , $t_f$	0 to 500	ns	V <sub>CC</sub> = 4.5 V
		0 to 400		V <sub>CC</sub> = 6.0 V

Note: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

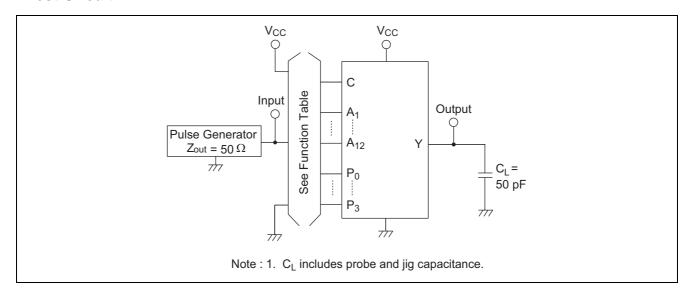
### **Electrical Characteristics**

			Т	a = 25°	С	Ta = -40 to+85°C			
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	2.0	1.5	_	_	1.5	_	V	
		4.5	3.15	_	_	3.15	_		
		6.0	4.2	_	_	4.2	_		
	$V_{IL}$	2.0	_	_	0.5	_	0.5	V	
		4.5		-	1.35	_	1.35		
		6.0	_	_	1.8	_	1.8		
Output voltage	$V_{OH}$	2.0	1.9	2.0	_	1.9	_	V	Vin = $V_{IH}$ or $V_{IL}$ $I_{OH} = -20 \mu A$
		4.5	4.4	4.5	_	4.4	_		
		6.0	5.9	6.0	_	5.9	_		
		4.5	4.18	_	_	4.13	_		$I_{OH} = -4 \text{ mA}$
		6.0	5.68	_	_	5.63	_		$I_{OH} = -5.2 \text{ mA}$
	V <sub>OL</sub>	2.0	_	0.0	0.1	_	0.1	V	$Vin = V_{IH} \text{ or } V_{IL} \mid I_{OL} = 20 \mu A$
		4.5	_	0.0	0.1	_	0.1		
		6.0	_	0.0	0.1	_	0.1		
		4.5	_	_	0.26	_	0.33		$I_{OL} = 4 \text{ mA}$
		6.0	_	_	0.26	_	0.33		$I_{OL} = 5.2 \text{ mA}$
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V <sub>CC</sub> or GND
Quiescent supply current	Icc	6.0	_	_	4.0	_	40	μА	Vin = $V_{CC}$ or GND, lout = $0 \mu A$

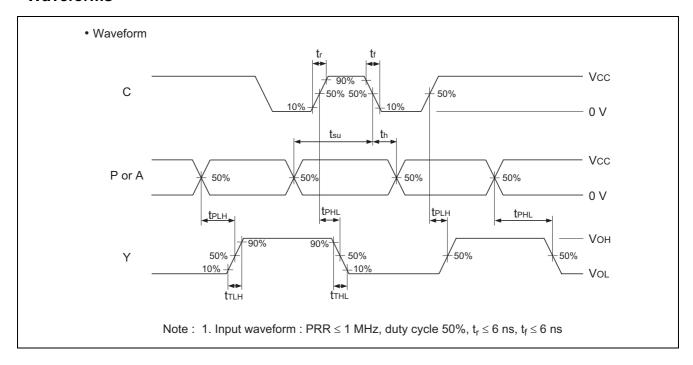
# Switching Characteristics ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ ns}$ )

			Т	a = 25°	С	Ta = -40	to +85°C		
Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t <sub>PLH</sub>	2.0	_	_	330	_	410	ns	P to Y
time	t <sub>PHL</sub>	4.5	_	26	66	_	82		
		6.0	_	_	56	_	70		
	t <sub>PLH</sub>	2.0	_	_	210	_	265	ns	A to Y
	t <sub>PHL</sub>	4.5	_	19	42	_	53		
		6.0	_	_	36	_	45		
	t <sub>PLH</sub>	2.0	_	_	150	_	190	ns	C to Y
	t <sub>PHL</sub>	4.5	_	18	30	_	38		
		6.0	_	_	26	_	33		
Setup time	t <sub>SU</sub>	2.0	100	_	_	125	_	ns	A to C
		4.5	20	12	_	25	_		
		6.0	17	_	_	21	_		
Output rise/fall	t <sub>TLH</sub>	2.0	_	_	75	_	95	ns	
time	t <sub>THL</sub>	4.5	_	6	15	_	19		
		6.0	_	_	13	_	16		
Input capacitance	Cin	_	_	5	10	_	10	pF	

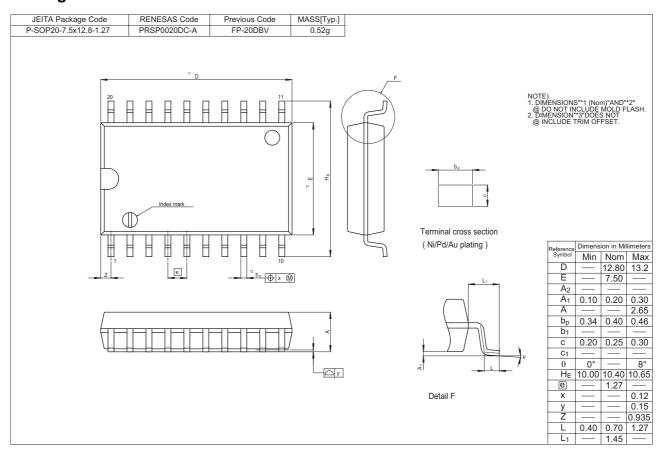
#### **Test Circuit**



#### **Waveforms**



#### **Package Dimensions**



#### Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Keep safety first in your circuit designs!

1. Renesas Technology Corp. puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage.

Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

- Notes regarding these materials

  1. These materials are intended as a reference to assist our customers in the selection of the Renesas Technology Corp. product best suited to the customer's application; they do not convey any license under any intellectual property rights, or any other rights, belonging to Renesas Technology Corp. or a third party.

  2. Renesas Technology Corp. assumes no responsibility for any damage, or infringement of any third-party's rights, originating in the use of any product data, diagrams, charts, programs, algorithms, or circuit application examples contained in these materials.

  3. All information contained in these materials, including product data, diagrams, charts, programs and algorithms represents information on products at the time of publication of these materials, and are subject to change by Renesas Technology Corp. without notice due to product improvements or other reasons. It is therefore recommended that customers contact Renesas Technology Corp. or an authorized Renesas Technology Corp. product distributor for the latest product information before purchasing a product listed herein.

  The information described here may contain technical inaccuracies or typographical errors.

  Renesas Technology Corp. assumes no responsibility for any damage, liability, or other loss rising from these inaccuracies or errors.

  Please also pay attention to information published by Renesas Technology Corp. by various means, including the Renesas Technology Corp. Semiconductor home page (http://www.renesas.com).

- home page (http://www.renesas.com).

  4. When using any or all of the information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as a total system before making a final decision on the applicability of the information and products. Renesas Technology Corp. assumes no responsibility for any damage, liability or other loss resulting from the information contained herein.

  5. Renesas Technology Corp. semiconductors are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact Renesas Technology Corp. or an authorized Renesas Technology Corp. product distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.
- use.

  6. The prior written approval of Renesas Technology Corp. is necessary to reprint or reproduce in whole or in part these materials.

  7. If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination.

  Any diversion or reexport contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited.

  8. Please contact Renesas Technology Corp. for further details on these materials or the products contained therein.



**RENESAS SALES OFFICES** 

http://www.renesas.com

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

**Renesas Technology America, Inc.** 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.

Neitesas Technology (offangriar) 63., Ed. Unit 204, 205, AZIACenter, No. 1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

**Renesas Technology Taiwan Co., Ltd.**10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

© 2006 Renesas Technology Corn. All rights reserved. Printed in Japan